

Heisener.com

MT47H512M4THN-25E:M

MT47H512M4THN-25E:M Information

Part NumberMT47H512M4THN-25E:MManufacturerMicron Technology Inc.CategoryIntegrated Circuits (ICs)

Memory

Description IC DRAM 2G PARALLEL 400MHZ

Package -

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









MT47H512M4THN-25E:M Specifications

Manufacturer Part Number	MT47H512M4THN-25E:M
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs)
	Memory
Package	-
Series	-
Memory Type	Volatile
Memory Format	DRAM
Technology	SDRAM - DDR2
Memory Size	2Gb (512M x 4)
Memory Interface	Parallel
Clock Frequency	400MHz
Write Cycle Time - Word, Page	15ns
Access Time	400ps
Voltage - Supply	1.7 V ~ 1.9 V
Operating Temperature	0°C ~ 85°C (TC)
Mounting Type	-
Package / Case	-
Supplier Device Package	-
	Report errors?

MT47H512M4THN-25E:M Guarantees



Ouality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MT47H512M4THN-25E:M Payment Methods



















MT47H512M4THN-25E:M Shipping Methods













If you have any question about MT47H512M4THN-25E:M, please do not hesitate to contact us!

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